Unit: mm

TOSHIBA Field-Effect Transistor Silicon N / P Channel MOS Type

SSM6L35FU

- High-Speed Switching Applications
- Analog Switch Applications

N-ch: 1.2-V drive
P-ch: 1.2-V drive
N-ch, P-ch, 2-in-1

• Low ON-resistance Q1 N-ch: R_{on} = 20 Ω (max) (@V_{GS} = 1.2 V)

: $R_{on} = 8 \Omega \text{ (max) } (@V_{GS} = 1.5 \text{ V})$

: $R_{on} = 4 \Omega \text{ (max) } (@V_{GS} = 2.5 \text{ V})$

: $R_{on} = 3 \Omega \text{ (max) } (@V_{GS} = 4.0 \text{ V})$

Q2 P-ch: R_{on} = 44 Ω (max) (@V_{GS} = -1.2 V)

: R_{on} = 22 Ω (max) (@V_{GS} = -1.5 V)

: $R_{on} = 11 \Omega \text{ (max) } (@V_{GS} = -2.5 \text{ V})$

: $R_{on} = 8 \Omega \text{ (max) } (@V_{GS} = -4.0 \text{ V})$

Q1 Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Drain-source voltage	V_{DSS}	20	٧	
Gate-source voltage		V_{GSS}	±10	V
Drain current	DC	I _D	180	mA
	Pulse	I _{DP}	360	IIIA

Q2 Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Drain-source voltage	V_{DSS}	-20	V	
Gate-source voltage		V_{GSS}	±10	V
Drain current	DC	I _D	-100	mA
	Pulse	I_{DP}	-200	IIIA

Absolute Maximum Ratings (Ta = 25 °C) (Common to the Q1, Q2)

Characteristics	Symbol	Rating	Unit	
Drain power dissipation	P _D (Note 1)	200	mW	
Channel temperature	T _{ch}	150	°C	
Storage temperature range	T _{stg}	-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating

1.SOURCE 1 4.SOURCE 2 2.GATE 1 5.GATE 2 3.DRAIN 2 6.DRAIN 1

2-2J1C

Weight: 6.8 mg (typ.)

JEDEC JEITA TOSHIBA

Start of commercial production 2008-03

Q1 Electrical Characteristics (Ta = 25°C)

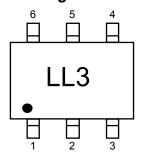
Charac	eteristics	Symbol	Test Condition		Min	Тур.	Max	Unit
Gate leakage curre	ent	I _{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0 \text{ V}$		_	_	±10	μΑ
Drain-source brea	kdown voltage	V (BR) DSS	$I_D = 0.1 \text{ mA}, V_{GS} = 0V$		20	_	_	V
Drain cutoff curren	t	I _{DSS}	V _{DS} = 20 V, V _{GS} = 0V		_	_	1	μΑ
Gate threshold vol	tage	V_{th}	$V_{DS} = 3 \text{ V}, I_{D} = 1 \text{ mA}$		0.4	_	1.0	V
Forward transfer admittance		Y _{fs}	$V_{DS} = 3 \text{ V}, I_{D} = 50 \text{ mA}$	(Note 2)	115	_	_	mS
			I _D = 50 mA, V _{GS} = 4 V	(Note 2)	_	1.5	3	Ω
Drain aguras ON	Drain-source ON-resistance		$I_D = 50 \text{ mA}, V_{GS} = 2.5 \text{ V}$	(Note 2)	_	2	4	
Drain-source ON-			$I_D = 5 \text{ mA}, V_{GS} = 1.5 \text{ V}$	(Note 2)	_	3	8	
			I _D = 5 mA, V _{GS} = 1.2 V	(Note 2)	_	5	20	
Input capacitance		C _{iss}	V _{DS} = 3 V, V _{GS} = 0V, f = 1 MHz		-	9.5	_	pF
Reverse transfer capacitance		C _{rss}			-	4.1	_	
Output capacitance		Coss			-	9.5	_	
Switching time	Turn-on time	t _{on}	$V_{DD} = 3 \text{ V}, I_D = 50 \text{ mA},$ $V_{GS} = 0 \text{ to } 2.5 \text{ V}$		-	115	_	
	Turn-off time	t _{off}			_	300	_	ns
Drain-source forward voltage		V _{DSF}	$I_D = -180 \text{ mA}, V_{GS} = 0V$	(Note 2)	_	-0.9	-1.2	V

Q2 Electrical Characteristics (Ta = 25°C)

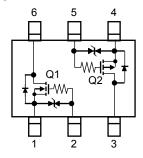
Charac	cteristics	Symbol	Test Condition		Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0 \text{ V}$			_	±10	μΑ
Drain-source brea	kdown voltage	V (BR) DSS	I _D = -0.1 mA, V _{GS} = 0 V		-20	_	_	V
Drain cutoff curren	t	I _{DSS}	V _{DS} = -20 V, V _{GS} = 0 V		_	_	-1	μА
Gate threshold vol	tage	V _{th}	$V_{DS} = -3 \text{ V}, I_{D} = -1 \text{ mA}$		-0.4	_	-1.0	V
Forward transfer admittance		Y _{fs}	$V_{DS} = -3 \text{ V}, I_{D} = -50 \text{ mA}$	(Note 2)	77	_	_	mS
Drain-source ON-resistance		R _{DS} (ON)	$I_D = -50 \text{ mA}, V_{GS} = -4 \text{ V}$	(Note 2)	_	4.3	8	Ω
			$I_D = -50 \text{ mA}, V_{GS} = -2.5 \text{ V}$	(Note 2)	-	5.6	11	
			$I_D = -5 \text{ mA}, V_{GS} = -1.5 \text{ V}$	(Note 2)	-	8.2	22	
			$I_D = -2 \text{ mA}, V_{GS} = -1.2 \text{ V}$	(Note 2)	-	11	44	
Input capacitance		C _{iss}	V _{DS} = -3 V, V _{GS} = 0 V, f = 1 MHz		-	12.2	_	
Reverse transfer capacitance		C _{rss}			_	6.5	_	pF
Output capacitance		Coss			_	10.4	_	
Switching time	Turn-on time	t _{on}	$V_{DD} = -3 \text{ V}, I_D = -50 \text{ mA},$ $V_{GS} = 0 \text{ to } -2.5 \text{ V}$		_	175	_	
	Turn-off time	t _{off}			_	251	_	ns
Drain-source forward voltage		V _{DSF}	I _D = 100 mA, V _{GS} = 0 V	(Note 2)	_	0.83	1.2	V

Note 2: Pulse test

Marking



Equivalent Circuit (top view)

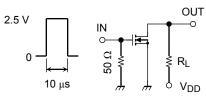


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Q1 Switching Time Test Circuit

(a) Test Circuit



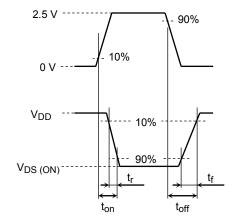
$$\begin{split} &V_{DD} = 3 \ V \\ &Duty \leq 1\% \\ &V_{IN} \text{: } t_r, \, t_f < 5 \text{ ns} \\ &(Z_{out} = 50 \ \Omega) \end{split}$$

Common Source

 $Ta = 25^{\circ}C$

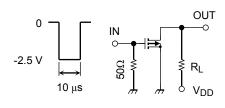


(c) V_{OUT}



Q2 Switching Time Test Circuit

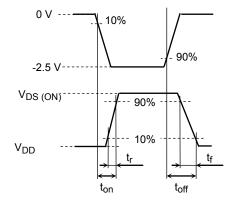
(a) Test Circuit



$$\begin{split} V_{DD} &= -3 \text{ V} \\ \text{Duty} &\leq 1\% \\ V_{IN} \text{: } t_r, \, t_f < 5 \text{ ns} \end{split}$$

 $(Z_{out} = 50 \Omega)$ Common Source (b) V_{IN}

(c) V_{OUT}



Q1 Usage Considerations

 $Ta = 25^{\circ}C$

Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (1 mA for the Q1 of the SSM6L35FU). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

Take this into consideration when using the device.

Q2 Usage Considerations

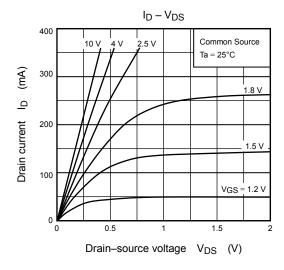
Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (-1 mA for the Q2 of the SSM6L35FU). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

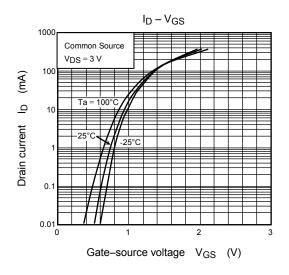
Take this into consideration when using the device.

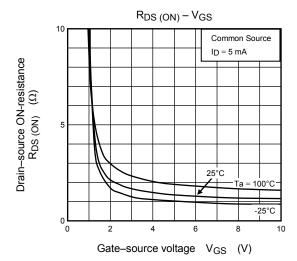
Handling Precaution

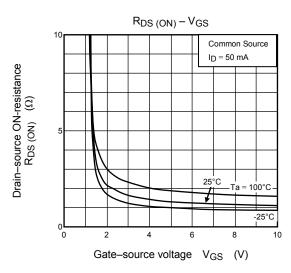
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

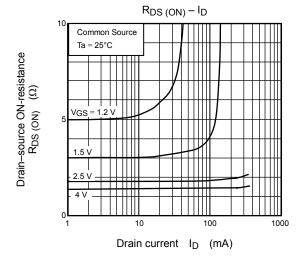
Q1 (N-ch MOSFET)

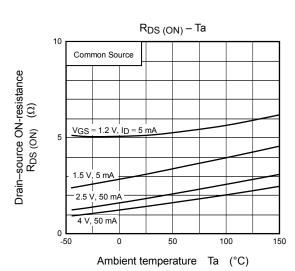




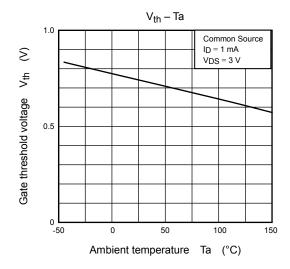


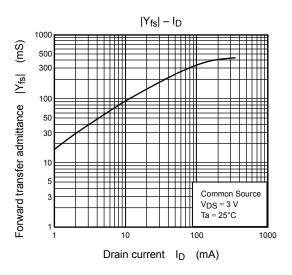


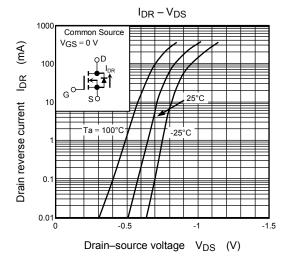


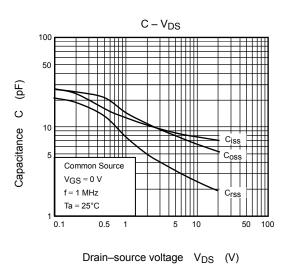


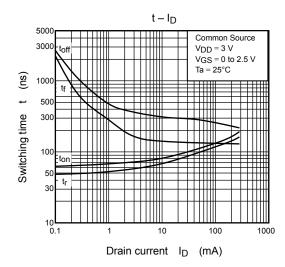
Q1 (N-ch MOSFET)





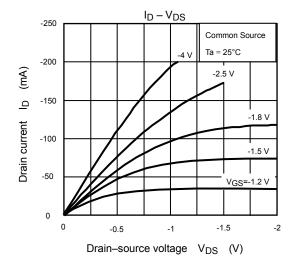


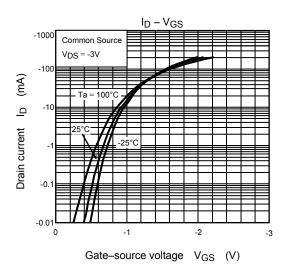


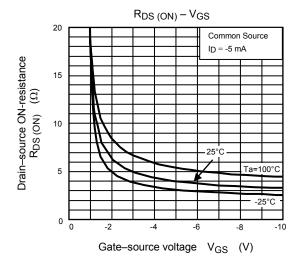


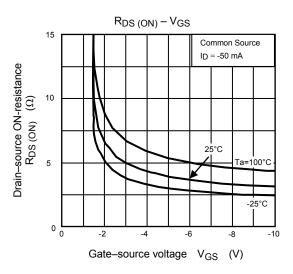
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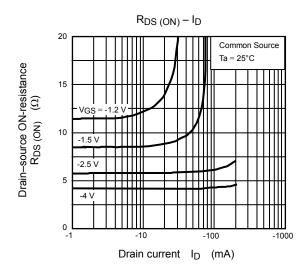
Q2 (P-ch MOSFET)

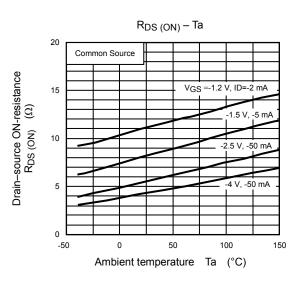






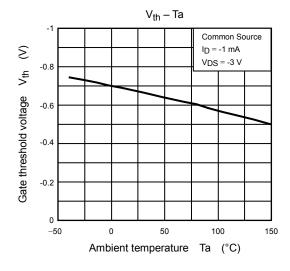


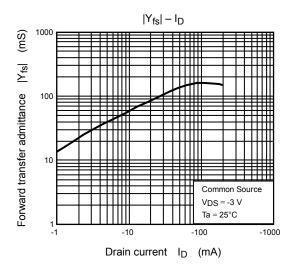


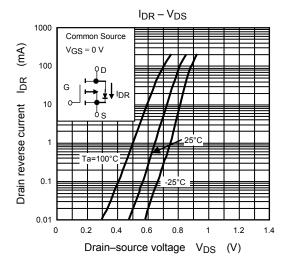


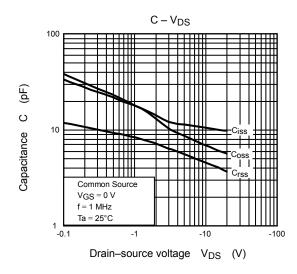
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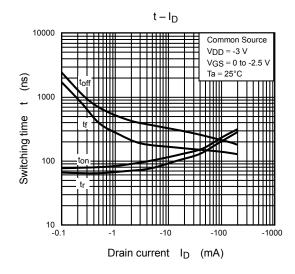
Q2 (P-ch MOSFET)

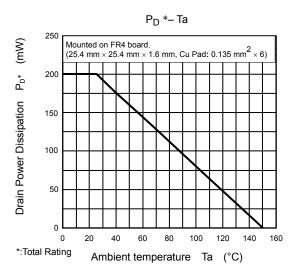












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